

# MBR840CT – MBR8200CT

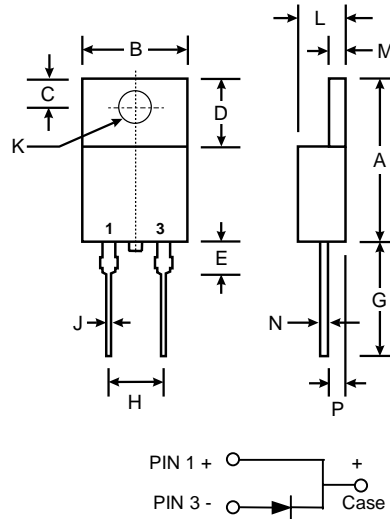
## 8.0 A SCHOTTKY BARRIER DIODE

### Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O

### Mechanical Data

- Case: TO-220AC, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Mounting Position: Any
- **Lead Free: For RoHS / Lead Free Version**



TO-220AC		
Dim	Min	Max
A	14.22	15.88
B	9.57	10.57
C	2.54	3.43
D	5.80	6.80
E	—	6.35
G	12.70	14.73
H	4.88	5.28
J	0.51	1.14
K	3.53 $\varnothing$	4.14 $\varnothing$
L	3.56	4.83
M	1.07	1.47
N	0.30	0.64
P	2.03	2.92
All Dimensions in mm		

### Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.  
For capacitive load, derate current by 20%.

Characteristic	Symbol	MBR 840CT	MBR 845CT	MBR 850CT	MBR 860CT	MBR 880CT	MBR 8100CT	MBR 8150CT	MBR 8200CT	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	40	45	50	60	80	100	150	200	V
RMS Reverse Voltage	$V_{R(RMS)}$	28	31	35	42	56	70	105	140	V
Average Rectified Output Current @ $T_L = 100^\circ\text{C}$ (Note 1)	$I_o$	8.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	100				120				A
Forward Voltage @ $I_F = 8\text{A}$	$V_{FM}$	0.70	0.80		0.85		0.92		V	
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 100^\circ\text{C}$	$I_{RM}$	0.1 20								mA
Typical Junction Capacitance (Note 2)	$C_j$	350	280		200				pF	
Typical Thermal Resistance (Note 1)	$R_{\theta JA}$	3.5				2.0				$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_j, T_{STG}$	-65 to +150								$^\circ\text{C}$

Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.  
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

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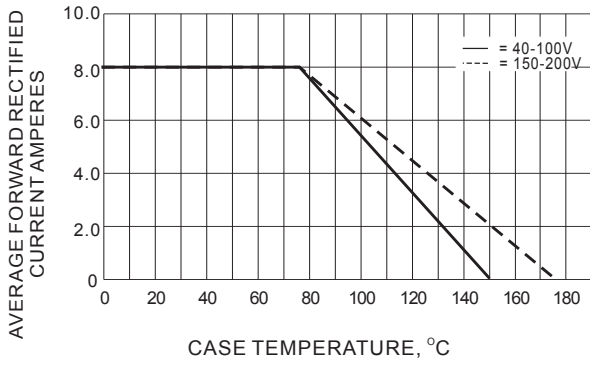


Fig.1- FORWARD CURRENT DERATING CURVE

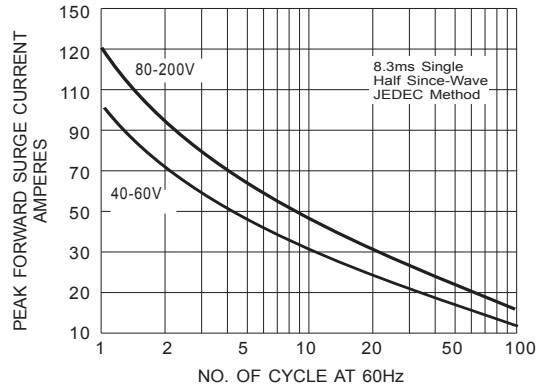


Fig.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

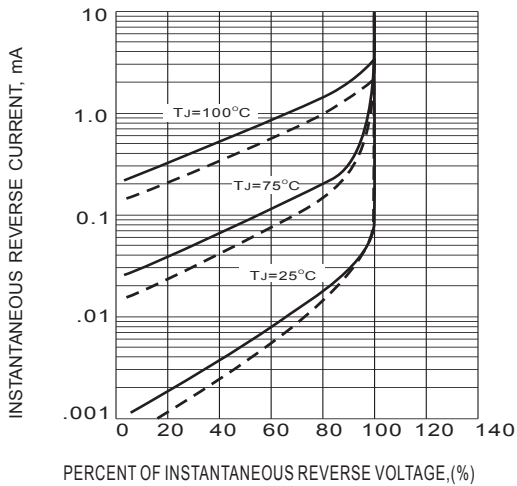


Fig.3- TYPICAL REVERSE CHARACTERISTICS

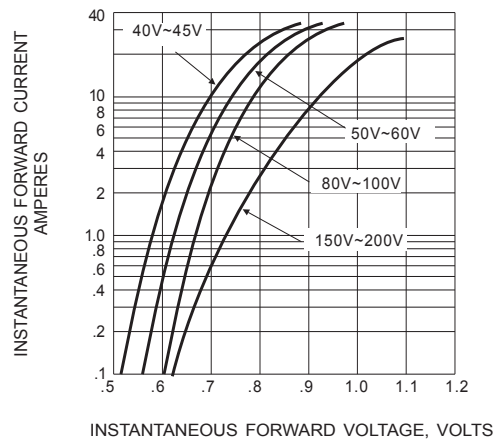


Fig.4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS